



RoHS

Achieving the best system cost in Mid/High Power

Mid-Power LED – 3020 Series

STW8B12B (Cool, Neutral, Warm)

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Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension.
 Package Size : 3.0x2.0x0.6mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

- Thermally Enhanced Package Design
- Mid Power to High Power up to 0.23W
- Max. Driving Current 80mA
- Compact Package Size
- High Color Quality with CRI Min. 80
- RoHS compliant

Key Applications

- Interior lighting
- General lighting
- Indoor and Outdoor displays
- Architectural and Decorative lighting

Table 1. Product Selection Table

Part Number		ССТ		
Part Number	Color	Min.	Тур.	Max.
STW8B12B	Cool White	4700K	5600K	7000K
STW8B12B	Neutral White	3700K	4200K	4700K
STW8B12B	Warm White	2600K	3000K	3700K



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Performance Characteristics

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Part Number	CCT (K) ^[1]	RANK		Intensity ^[2] (cd)	Luminou Φ _v (CRI R _a
	Тур.		Min	Max	Min	Max	Min.
		MO	4.0	4.5	12.0	13.5	80
	6500	M5	4.5	5.0	13.5	15	80
	0300	NO	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80
		MO	4.0	4.5	12.0	13.5	80
	5600	M5	4.5	5.0	13.5	15	80
	5600	NO	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80
		M0	4.0	4.5	12.0	13.5	80
	5000	M5	4.5	5.0	13.5	15	80
	5000	N0	5.0	5.5	15	16.5	80
STW8B12B		N5	5.5	6.0	16.5	18	80
S100812B		M0	4.0	4.5	12.0	13.5	80
	4500	M5	4.5	5.0	13.5	15	80
	4500	N0	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80
		MO	4.0	4.5	12.0	13.5	80
	4000	M5	4.5	5.0	13.5	15	80
	4000	N0	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80
		MO	4.0	4.5	12.0	13.5	80
	0500	M5	4.5	5.0	13.5	15	80
	3500	N0	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80

Table 2. Product Selection Guide, $\rm I_F=40mA$, $\rm T_a=25^{o}C,~RH30\%$

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate : ± 0.007
- (2) Seoul Semiconductor maintains a tolerance of ±7% on Intensity and power measurements. The luminous intensity IV was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.
- (3) Calculated performance values are for reference only.

Performance Characteristics

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Part Number	CCT (K) [1]	RANK		Intensity ^[2] (cd)	Luminou Φ _v (CRI R _a
	Тур.		Min	Max	Min	Max	Min.
		MO	4.0	4.5	12.0	13.5	80
		M5	4.5	5.0	13.5	15	80
	3000	N0	5.0	5.5	15	16.5	80
STW8B12B		N5	5.5	6.0	16.5	18	80
STW0B12B		MO	4.0	4.5	12.0	13.5	80
	0700	M5	4.5	5.0	13.5	15	80
	2700	N0	5.0	5.5	15	16.5	80
		N5	5.5	6.0	16.5	18	80

Table 2. Product Selection Guide, $I_{\rm F}{=}40mA$, $T_{\rm a}$ = 25°C, RH30%

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate : ± 0.007
- (2) Seoul Semiconductor maintains a tolerance of ±7% on Intensity and power measurements. The luminous intensity IV was measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.
- (3) Calculated performance values are for reference only.

Performance Characteristics

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Deserved	Currente al		Value		Unit
Parameter	Symbol	Symbol Min.		Max.	
Forward Current	I _F	-	40	80	mA
Forward Voltage	V _F (40mA)	2.8		3.3	V
Luminous Intensity (3,700~7,000 K)	I _v (40mA)	-	5.05 (15.1)	-	cd (Im)
Luminous Intensity (2,600~3,700 K)	I _v (40mA)	-	4.50 (13.5)	-	cd (Im)
Color Rendering Index [1]	R _a	80	-	90	-
Viewing Angle ^[2]	20 _{1/2}		120		
Power Dissipation	P _D	-	264		mW
Junction Temperature	T _j	-	-	125	°C
Operating Temperature	T _{opr}	- 40	-	+ 85	٥C
Storage Temperature	T _{stg}	- 40	-	+ 100	°C
Thermal resistance (J to S) [3]	Rθ _{J-S}	-	25	-	°C/W

Table 3. Characteristics, I_F =40mA , T_a = 25°C, RH30%

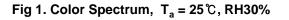
- (1) Tolerance is ± 2.0 on CRI measurements.
- (2) $2\Theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity
- (3) Thermal resistance: Rth_{JS} (Junction to Solder)
- LED's properties might be different from suggested values like above and below tables if operation condition will be exceeded our parameter range. Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product.
- All measurements were made under the standardized environment of Seoul Semiconductor.

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3020 - Mid-Power LED

Relative Spectral Distribution

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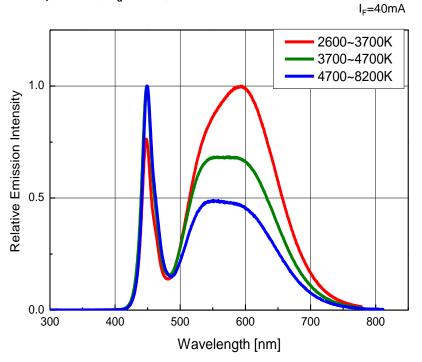
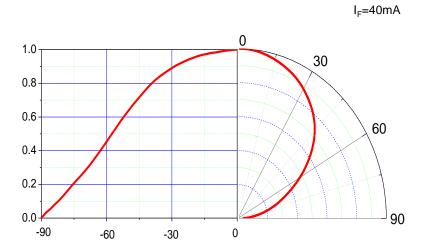


Fig 2. Viewing Angle Distribution





Forward Current Characteristics

Fig 3. Forward Voltage vs. Forward Current , $\rm T_a=25\,^\circ\!\!C$

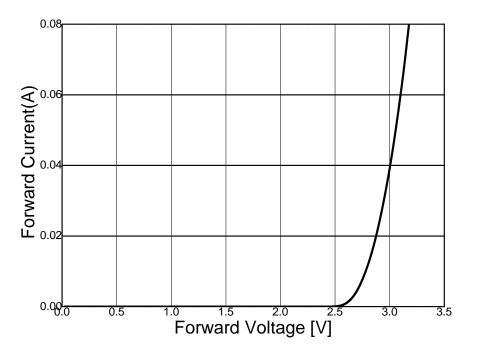
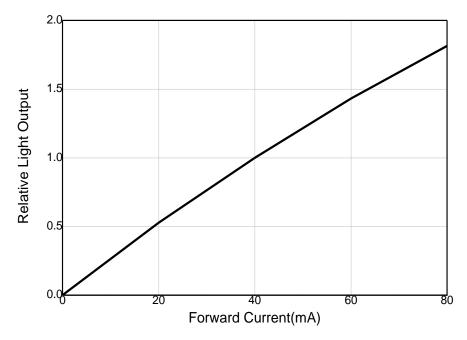


Fig 4. Forward Current vs. Relative Luminous Flux, $T_a=25$ °C



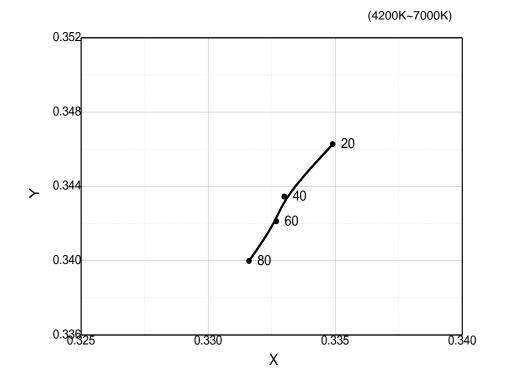
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Product Data Sheet

3020 - Mid-Power LED

Forward Current Characteristics

Fig 5. Forward Current vs. CIE X, Y Shift , $T_a=25$ °C



Rev1.0, March 17, 2014

Product Data Sheet

3020 – Mid-Power LED

Junction Temperature Characteristics

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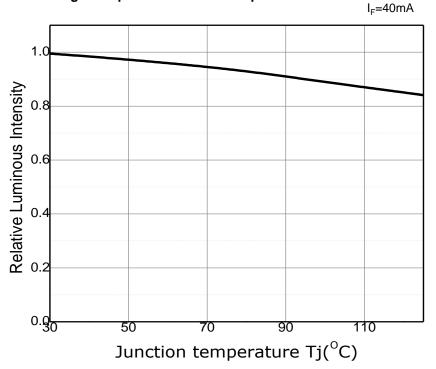
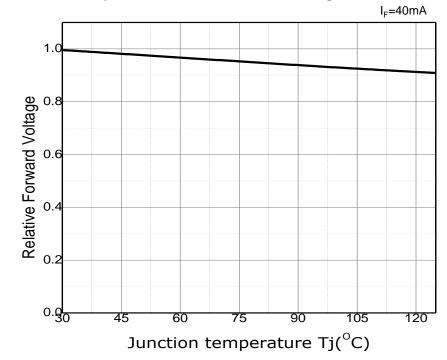


Fig 6. Relative Light Output vs. Junction Temperature

Fig 7. Junction Temperature vs. Relative Forward Voltage

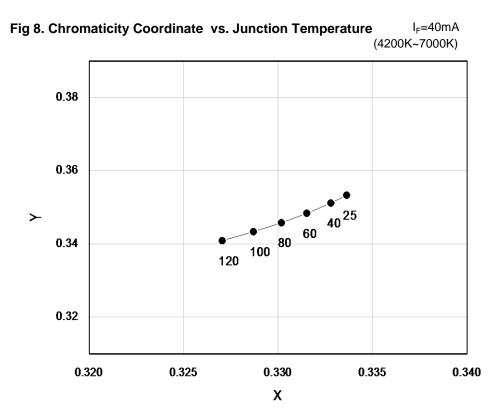


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3020 - Mid-Power LED

Junction Temperature Characteristics





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Ambient Temperature Characteristics

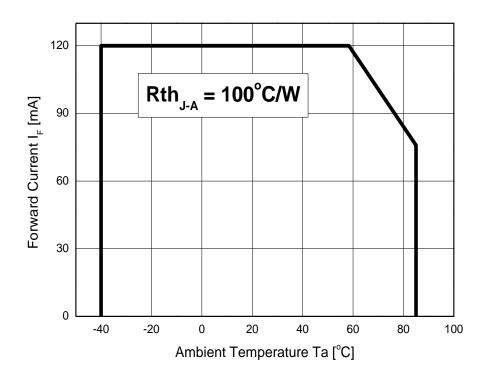


Fig 9. Maximum Forward Current vs. Ambient Temperature

Available Ranks

Color Bin Structure

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Table 4. Bin Code description

Part Number		us Intensity PI _F = 40mA	/ (cd)	Color Chromaticity Coordinate	Typical Forward Voltage (V _F) @ I _F = 40mA		
	Bin Code	Min.	Max.	@ I _F = 40mA	Bin Code	Min.	Max.
	L5	3.5	4.0		Y2	2.8	2.9
	MO	4.0	4.5		Y3	2.9	3.0
STW8B12C	M5	4.5	5.0	Refer to page.14	Z1	3.0	3.1
	NO	5.0	5.5		Z2	3.1	3.2
	N5	5.5	6.0		Z3	3.2	3.3

Table 5. Intensity rank distribution

IV Rank ССТ CIE 6000~7000 K L5 M0 N0 N5 A M5 5300~6000 K В L5 M5 N0 N5 M0 С L5 4700~5300 K M0 M5 N0 N5 4200~4700 K D L5 M0 M5 N0 N5 3700~4200 K L5 Е M0 M5 N0 N5 3200~3700 K F L5 M0 M5 N0 N5 G 2900~3200 K L5 M0 M5 N0 N5 2600~2900 K Н L5 M0 M5 N0 N5

Notes :

(1) All measurements were made under the standardized environment of Seoul Semiconductor.

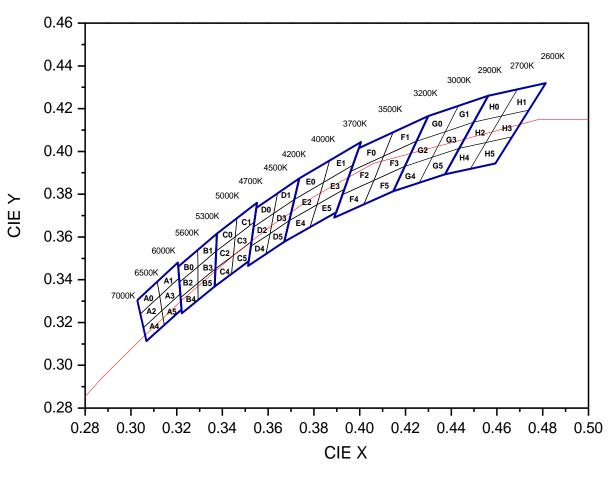
(2) Seoul Semiconductor sorts the LED package according to the luminous intensity IV.

(3) The lumen table is only for reference.



Color Bin Structure

Fig 10. CIE Chromaticity Diagram $T_a=25$ °C, $I_F=40$ mA



(1) Energy Star binning applied to all 2600~7000K.

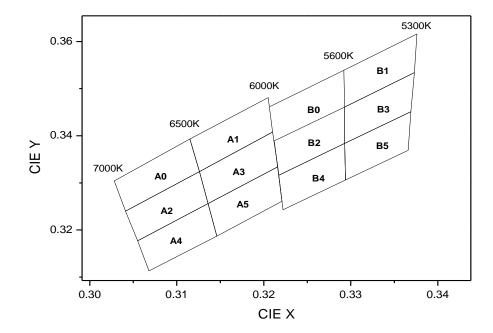
(2) Measurement Uncertainty of the Color Coordinates : \pm 0.007



Color Bin Structure

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<I_F=40mA, T_a=25℃>

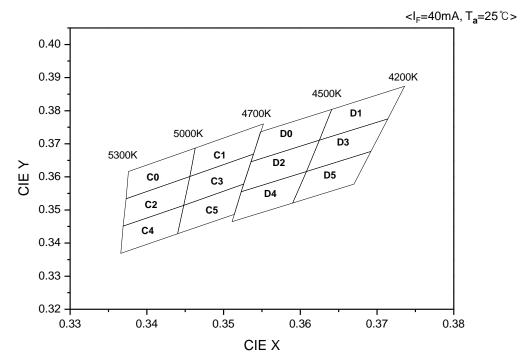


A	0	A	.1	A	2	A	3
CIE X	CIE Y						
0.3028	0.3304	0.3115	0.3393	0.3041	0.324	0.3126	0.3324
0.3041	0.324	0.3126	0.3324	0.3055	0.3177	0.3136	0.3256
0.3126	0.3324	0.321	0.3408	0.3136	0.3256	0.3216	0.3334
0.3115	0.3393	0.3205	0.3481	0.3126	0.3324	0.321	0.3408
A	4	A	5	В	0	В	1
CIE X	CIE Y						
0.3055	0.3177	0.3136	0.3256	0.3207	0.3462	0.3292	0.3539
0.3068	0.3113	0.3146	0.3187	0.3212	0.3389	0.3293	0.3461
0.3146	0.3187	0.3221	0.3261	0.3293	0.3461	0.3373	0.3534
0.3136	0.3256	0.3216	0.3334	0.3292	0.3539	0.3376	0.3616
В	2	В	3	В	4	В	5
CIE X	CIE Y						
0.3212	0.3389	0.3293	0.3461	0.3217	0.3316	0.3293	0.3384
0.3217	0.3316	0.3293	0.3384	0.3222	0.3243	0.3294	0.3306
0.3293	0.3384	0.3369	0.3451	0.3294	0.3306	0.3366	0.3369
0.3293	0.3461	0.3373	0.3534	0.3293	0.3384	0.3369	0.3451

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Color Bin Structure

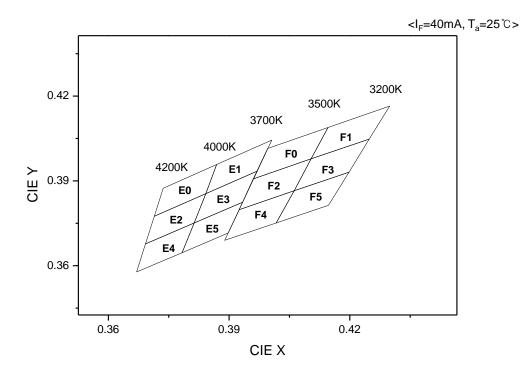


C	0	С	:1	С	2	С	3
CIE X	CIE Y						
0.3376	0.3616	0.3463	0.3687	0.3373	0.3534	0.3456	0.3601
0.3373	0.3534	0.3456	0.3601	0.3369	0.3451	0.3448	0.3514
0.3456	0.3601	0.3539	0.3669	0.3448	0.3514	0.3526	0.3578
0.3463	0.3687	0.3552	0.376	0.3456	0.3601	0.3539	0.3669
C	4	с	5	D	0	D	1
CIE X	CIE Y						
0.3369	0.3451	0.3448	0.3514	0.3548	0.3736	0.3641	0.3804
0.3366	0.3369	0.344	0.3428	0.3536	0.3646	0.3625	0.3711
0.344	0.3428	0.3514	0.3487	0.3625	0.3711	0.3714	0.3775
0.3448	0.3514	0.3526	0.3578	0.3641	0.3804	0.3736	0.3874
D	2	D	3	D	4	D	5
CIE X	CIE Y						
0.3536	0.3646	0.3625	0.3711	0.3523	0.3555	0.3608	0.3616
0.3523	0.3555	0.3608	0.3616	0.3511	0.3465	0.359	0.3521
0.3608	0.3616	0.3692	0.3677	0.359	0.3521	0.367	0.3578
0.3625	0.3711	0.3714	0.3775	0.3608	0.3616	0.3692	0.3677



Color Bin Structure

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E	0	E	1	E	2	E	3
CIE X	CIE Y						
0.3736	0.3874	0.3869	0.3958	0.3714	0.3775	0.3842	0.3855
0.3714	0.3775	0.3842	0.3855	0.3692	0.3677	0.3813	0.3751
0.3842	0.3855	0.397	0.3935	0.3813	0.3751	0.3934	0.3825
0.3869	0.3958	0.4006	0.4044	0.3842	0.3855	0.397	0.3935
E	4	E	5	F	0	F	1
CIE X	CIE Y						
0.3692	0.3677	0.3813	0.3751	0.3996	0.4015	0.4146	0.4089
0.367	0.3578	0.3783	0.3646	0.396	0.3907	0.4104	0.3978
0.3783	0.3646	0.3898	0.3716	0.4104	0.3978	0.4248	0.4048
0.3813	0.3751	0.3934	0.3825	0.4146	0.4089	0.4299	0.4165
F:	2	F	3	F	4	F	5
CIE X	CIE Y						
0.396	0.3907	0.4104	0.3978	0.3925	0.3798	0.4062	0.3865
0.3925	0.3798	0.4062	0.3865	0.3889	0.369	0.4017	0.3751
0.4062	0.3865	0.4198	0.3931	0.4017	0.3751	0.4147	0.3814
0.4104	0.3978	0.4248	0.4048	0.4062	0.3865	0.4198	0.3931

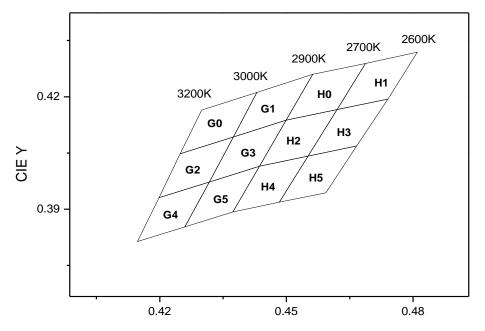


Product Data Sheet

3020 - Mid-Power LED

Color Bin Structure

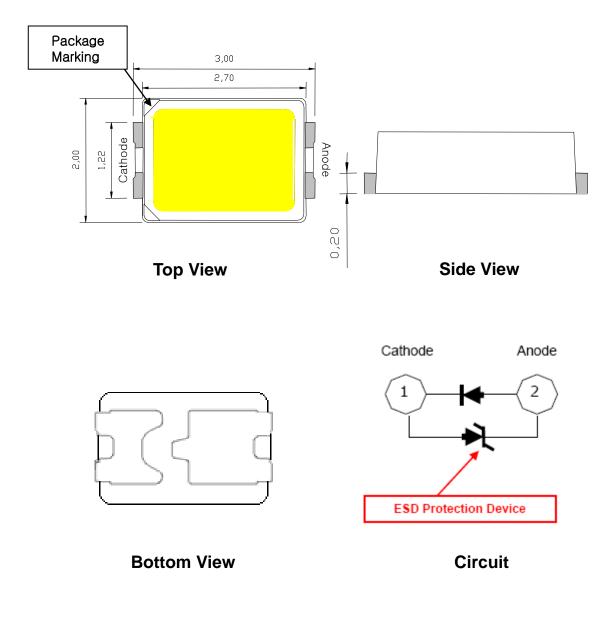
<I_F=40mA, T_a=25℃>



G	0	G	1	G	2	G	3
CIE X	CIE Y						
0.4299	0.4165	0.443	0.4212	0.4248	0.4048	0.4374	0.4093
0.4248	0.4048	0.4374	0.4093	0.4198	0.3931	0.4317	0.3973
0.4374	0.4093	0.4499	0.4138	0.4317	0.3973	0.4436	0.4015
0.443	0.4212	0.4562	0.426	0.4374	0.4093	0.4499	0.4138
G	4	G	5	н	0	н	1
CIE X	CIE Y						
0.4198	0.3931	0.4317	0.3973	0.4562	0.426	0.4687	0.4289
0.4147	0.3814	0.4259	0.3853	0.4499	0.4138	0.462	0.4166
0.4259	0.3853	0.4373	0.3893	0.462	0.4166	0.474	0.4194
0.4317	0.3973	0.4436	0.4015	0.4687	0.4289	0.481	0.4319
H	2	н	3	н	4	н	5
CIE X	CIE Y						
0.4499	0.4138	0.462	0.4166	0.4436	0.4015	0.4551	0.4042
0.4436	0.4015	0.4551	0.4042	0.4373	0.3893	0.4483	0.3919
0.4551	0.4042	0.4666	0.4069	0.4483	0.3919	0.4593	0.3944
0.462	0.4166	0.474	0.4194	0.4551	0.4042	0.4666	0.4069



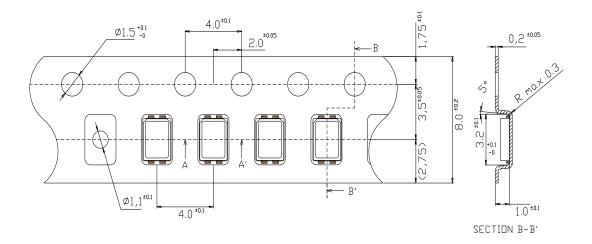
Mechanical Dimensions



- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is $\pm 0.2 \text{mm}$

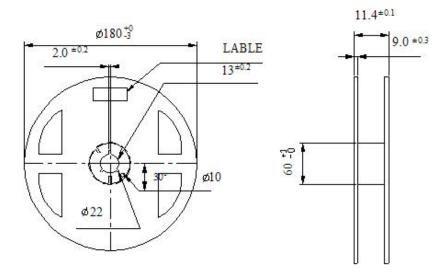


Reel Packaging





SECTION A-A'



(Tolerance: ± 0.2 , Unit: mm)

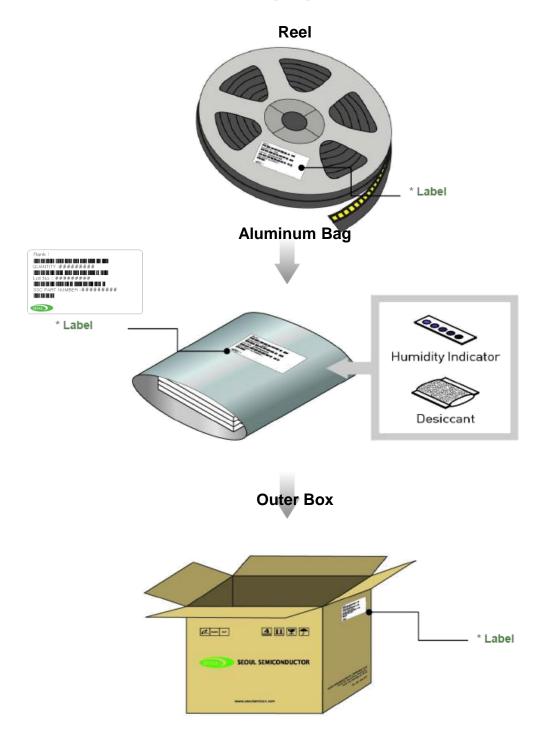
- (1) Quantity : Max 4,000pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$
- (3) Adhesion Strength of Cover Tape
- Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape.
- (4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.



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Emitter Tape & Reel Packaging



Emitter Tape & Reel Packaging

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Table 6. Part Numbering	System :	$X_1X_2X_3X_4X_5X_6X_7$
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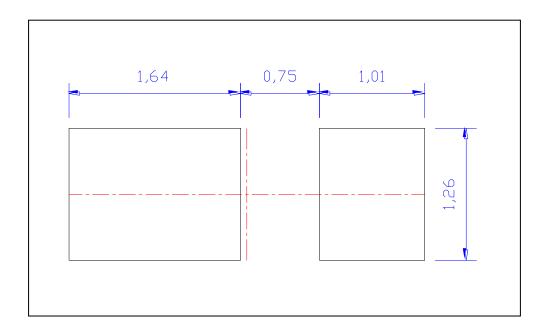
Part Number Code	Description	Part Number	Value
X ₁	Company	S	
X ₂	Top View LED series	т	
X ₃	Color Specification	W8	CRI 80
X4	Package series	В	B series
X ₅ X ₆	Characteristic code	12	
X ₇	Revision	В	

Table 7. Lot Numbering System $:Y_1Y_2Y_3Y_4Y_5Y_6Y_7Y_8Y_9Y_{10}-Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$

Lot Number Code	Description	Lot Number	Value
Y ₁ Y ₂	Year		
Y ₃	Month		
Y ₄ Y ₅	Day		
Y ₆	Top View LED series		
Y ₇ Y ₈ Y ₉ Y ₁₀	Mass order		
Y ₁₁ Y ₁₂ Y ₁₃ Y ₁₄ Y ₁₅ Y ₁₆ Y ₁₇	Internal Number		



Recommended Solder Pad



[Recommended Solder Pattern]

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) This drawing without tolerances are for reference only
- (4) Undefined tolerance is ± 0.1 mm

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3020 - Mid-Power LED

Reflow Soldering Characteristics

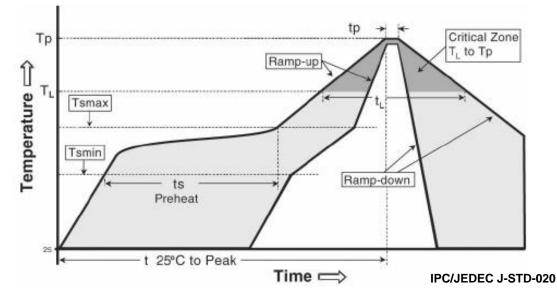


Table 8.

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Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_{smax} to T_p)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T _{smin}) - Temperature Max (T _{smax}) - Time (T _{smin} to T _{smax}) (t _s)	100 °C 150 °C 60-120 seconds	150 ℃ 200 ℃ 60-180 seconds
Time maintained above: - Temperature (T _L) - Time (t _L)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T _p)	215 ℃	260 ℃
Time within 5°C of actual Peak Temperature (t _p)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.



Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

SEOUL

To avoid the moisture penetration, we recommend store in a dry box with a desiccant .

The recommended storage temperature range is 5 $^\circ C$ to 30 $^\circ C$ and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMT techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

a. Recommend conditions after opening the package

- Sealing

- Temperature : 5 ~ 40 $^\circ\!\! C$ Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant changes, components should be dried for 10-12hr at $60\pm5\,^\circ$ C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication.

These products are dangerous if they are burned or shredded in the process of disposal.

It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.
- (11) The appearance and specifications of the product may be modified for improvement without notice.
- (12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.
- (13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy.

The result can be a significant loss of light output from the fixture.

Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

- (14) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (15) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.

If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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